

THE NEW 5V - 1Mb SRAM

The New 1Mb SRAM Die has ramped up into production. There are two major strategic aspects of this new die introduction. The first and most important strategy is our long-term commitment to the 5V SRAM product family. The other aspect is our commitment to continuous improvement. The new 5V 1Mb die features much lower power characteristics.



	IS61C1024AL 128K x 8 High Speed	IS62C1024AL 128K x 8 Low Power	IS61C6416AL 64K x 16 High Speed	Comments
Technology	0.15um 0.45um (old die)	0.15um 0.45um (old die)	0.15um 0.45um (old die)	Smaller Die Size
Standby Current	450uA 40mA (old die)	10uA 750uA (old die)	400uA 15mA (old die)	Lower Current
Operating Current	50mA 180mA (old die)	35mA 110mA (old die)	55mA 300mA (old die)	Lower Current
Packaging	SOJ, TSOP	SOP, TSOP	SOJ, TSOP	Drop in
Speed	12ns	35ns	12ns	
Temperature Support	Industrial Automotive	Industrial Automotive	Industrial Automotive	
Lead Free and Non-Lead Free	YES	YES	YES	RoHS Compliant
Status	Production	Production	Production	

Applications:

The device is used in a variety of applications including Industrial, Automotive, Telecom, and Networking.

Customers using the existing die, need to migrate to the new die. In addition, we have to look for new sockets based on the new power consumption numbers.

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